XP01215 (XP1215)

Silicon NPN epitaxial planar type

For switching/digital circuits

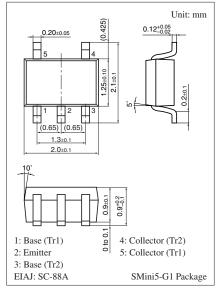
Features

- Two elements incorporated into one package (Emitter-coupled transistors with built-in resistor)
- Reduction of the mounting area and assembly cost by one half

Basic Part Number

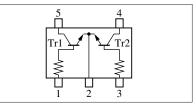
• UNR2215 (UN2215) × 2

Absolute Maximum Ratings $T_a = 25^{\circ}C$ Parameter Symbol Rating Unit V Collector-base voltage (Emitter open) V_{CBO} 50 Collector-emitter voltage (Base open) V_{CEO} 50 V 100 Collector current I_C mА 150 mW Total power dissipation \mathbf{P}_{T} Junction temperature Ti 150 °C Storage temperature T_{stg} -55 to +150 °C



Marking Symbol: 9M

Internal Connection



Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V _{CBO}	$I_{\rm C} = 10 \ \mu A, \ I_{\rm E} = 0$	50			V
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = 2 {\rm mA}, I_{\rm B} = 0$	50			V
Collector-base cutoff current (Emitter open)	I _{CBO}	$V_{CB} = 50 \text{ V}, I_E = 0$			0.1	μΑ
Collector-emitter cutoff current (Base open)	I _{CEO}	$V_{CE} = 50 \text{ V}, I_B = 0$			0.5	μΑ
Emitter-base cutoff current (Collector open)	I _{EBO}	$V_{EB} = 6 V, I_C = 0$			0.01	mA
Forward current transfer ratio	h _{FE}	$V_{CE} = 10 \text{ V}, \text{ I}_{C} = 5 \text{ mA}$	160		460	
h _{FE} Ratio *	h _{FE(Small}	$V_{CE} = 10 \text{ V}, \text{ I}_{C} = 5 \text{ mA}$	0.50	0.99		
	/Large)					
Collector-emitter saturation voltage	V _{CE(sat)}	$I_{C} = 10 \text{ mA}, I_{B} = 0.3 \text{ mA}$			0.25	V
Output voltage high-level	V _{OH}	$V_{CC} = 5 V, V_B = 0.5 V, R_L = 1 k\Omega$	4.9			V
Output voltage low-level	V _{OL}	$V_{CC} = 5 \text{ V}, \text{V}_{B} = 2.5 \text{V}, \text{R}_{L} = 1 \text{k}\Omega$			0.2	V
Input resistance	R ₁		-30%	10	+30%	kΩ
Transition frequency	f _T	$V_{CB} = 10 \text{ V}, I_E = -2 \text{ mA}, f = 200 \text{ MHz}$		150		MHz

Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

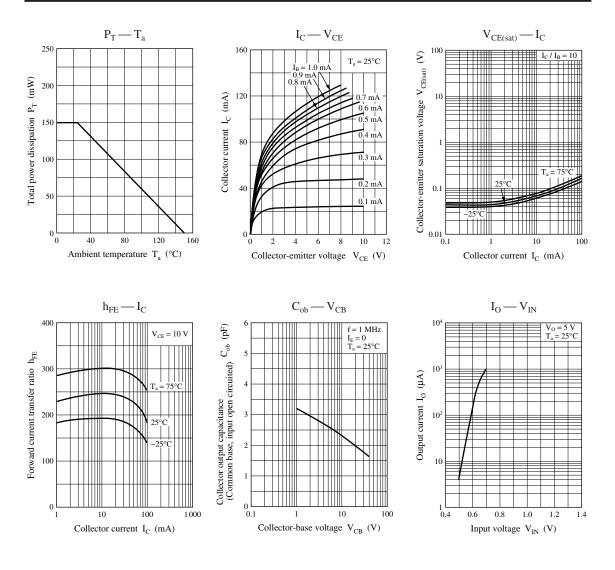
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

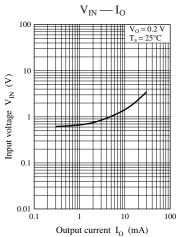
2. *: Ratio between 2 elements

Note) The part number in the parenthesis shows conventional part number.

XP01215







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